NSN 5961-00-836-7175

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-836-7175 **Inclosure Material:** Glass **Overall Length:** 0.510 millimeters **Terminal Length:** 0.260 millimeters **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method: Terminal Terminal Circle Diameter:** 0.370 millimeters **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 breakdown voltage, collector to emitter, sustained and 25.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 600.00 milliamperes zero-gate-voltage source current blank **Power Rating Per Characteristic:** 400.0 watts small-signal input power, common-emitter absolute **Maximum Operating Tempurature Per Measurement Point:** -55.0 degrees celsius case and 175.0 degrees celsius case **Special Features:** Low frequency low power pnp bjt; junction pattern arrangement: pnp **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli